





#### **60V PNP MEDIUM POWER TRANSISTOR IN SOT23**

### **Features and Benefits**

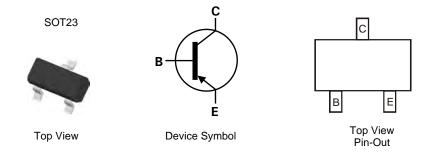
- BV<sub>CEO</sub> > -60V Breakdown Voltage
- 100V forward blocking voltage
- I<sub>C</sub> = -3A Continuous Collector Current,
- I<sub>CM</sub> = -9A Peak Pulse Current,
- Low saturation voltage, V<sub>CE(sat)</sub> < -85mV @ -1A</li>
- $R_{CE(sat)} = 58 \text{ m}\Omega$  for a low equivalent on-resistance
- 1.25W power dissipation using SuperSOT package
- Complementary part number ZXTN25060BFH
- Lead Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free, Green Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT23
- Case material: molded Plastic. "Green" molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.008 grams (Approximate)

### **Applications**

- MOSFET drivers
- Power switches
- Motor control



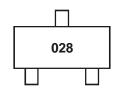
### Ordering Information (Note 3)

Product	Case	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP25060BFHTA	SOT23	7	8mm	3000

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc.'s "Green" Policy can be found on our website at http://www.diodes.com
- 3. For packaging details, go to our website at http://www.diodes.com/

## **Marking Information**



028 = Product Type Marking Code





### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-100	V
Collector-Emitter Voltage (forward blocking)	V <sub>CEX</sub>	-100	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-60	V
Emitter-Collector Voltage (reverse blocking)	V <sub>ECO</sub>	-7	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-3	Α
Peak pulse Current	I <sub>CM</sub>	-9	Α

### Thermal Characteristics @TA = 25°C unless otherwise specified

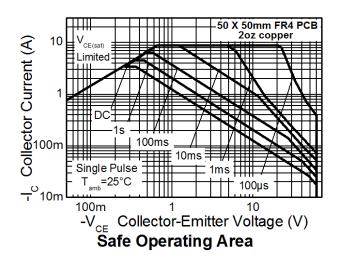
Characteristic	Symbol	Unit			
	(Note 4)		0.73		
	(Note 4)		5.84	1	
	(Note 5)		1.05	W	
Power Dissipation	(Note 5)	D	8.4		
Linear derating factor	(Note C)	P <sub>D</sub>	1.25		
	(Note 6)		9.6		
	(Note 7)		1.81		
	(Note 7)	(Note 7)	14.5		
	(Note 4)		171	°C/W	
The area I Decistor as I westing to Ambient	(Note 5)		119		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	100		
	(Note 7)		69		
Thermal Resistance, Junction to Lead	(Note 8)	$R_{\theta JL}$	74.95	°C/W	
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

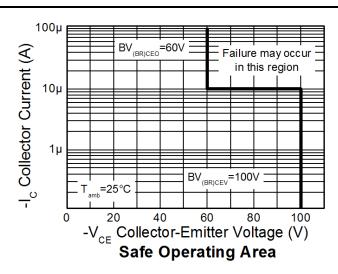
Notes:

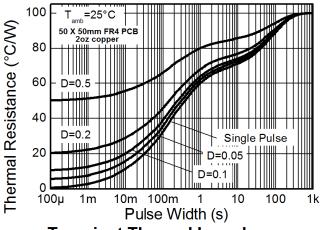
- 4. For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 5. Same as note (4), except the device is surface mounted on 25mm x 25mm with 2 oz copper. 6. Same as note (4), except the device is surface mounted on 50mm x 50mm with 2 oz copper.
- 7. Same as note (6), except the device is measured at t<5secs.
- 8. Thermal resistance from junction to solder-point (at the end of the collector lead).

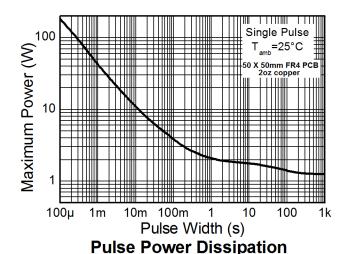


### **Thermal Characteristics**

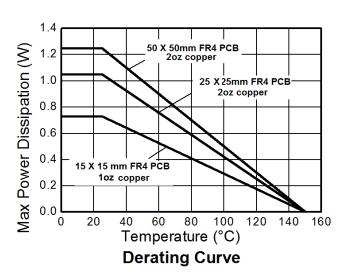
















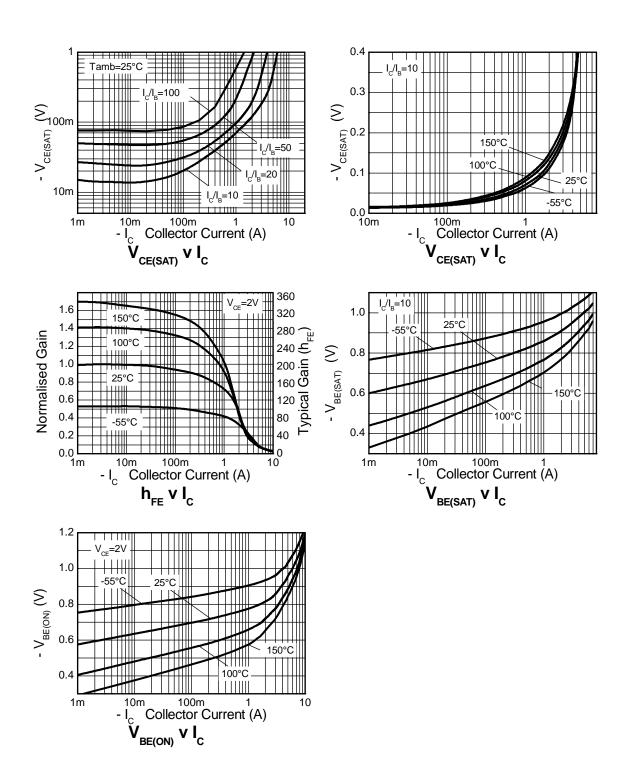
## Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-100	-120	-	V	I <sub>C</sub> = -100 μA
Collector-Emitter Breakdown Voltage (forward blocking)	BV <sub>CEX</sub>	-100	-120	-	V	$I_C = -100 \mu A$ , $R_{BE} < 1kΩ$ or $-0.25V < V_{BE} < 1V$
Collector-Emitter Breakdown Voltage (base open) (Note 9)	BV <sub>CEO</sub>	-60	-80	-	V	I <sub>C</sub> = -10mA
Emitter- Collector Breakdown Voltage (Reverse blocking) (Note 9)	BV <sub>ECO</sub>	-7	-8.6	-	V	Ι <sub>Ε</sub> = -100μΑ
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.1	-	V	I <sub>E</sub> = -100μA
Collector Cutoff Current	I <sub>CBO</sub>	-	< -1 -	-50 -20	nΑ μΑ	V <sub>CB</sub> = -80V V <sub>CB</sub> = -80V, T <sub>A</sub> = 100°C
Collector emitter Cutoff Current	I <sub>CEX</sub>	-	-	-100	nA	$V_{CE} = -80V$ , R <sub>BE</sub> < 1k $\Omega$ or -0.25V < V <sub>BE</sub> < 1V
Emitter Cutoff Current	I <sub>EBO</sub>	-	< -1	-50	nA	V <sub>EB</sub> = -6V
	h <sub>FE</sub>	100	200	300		I <sub>C</sub> = -10mA, V <sub>CE</sub> = -2V
Static Forward Current Transfer Ratio (Note 9)		75 30	150 60	-	-	$I_{C} = -1A$ , $V_{CE} = -2V$ $I_{C} = -3A$ , $V_{CE} = -2V$
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	-	-940	-1040	mV	I <sub>C</sub> = -3A, I <sub>B</sub> = -300mA
Base-Emitter turn-on Voltage (Note 9)	V <sub>BE(on)</sub>	-	-830	-930	mV	Ic = -3A, VcE = -2V
	V <sub>CE(sat)</sub>	-	-45 -100	-55 -135	mV	$I_C = -0.5A$ , $I_B = -50mA$ $I_C = -0.5A$ , $I_B = -10mA$
Collector-Emitter Saturation Voltage (Note 9)		-	-70 -175	-85 -235		I <sub>C</sub> = -1A, I <sub>B</sub> = -100mA I <sub>C</sub> = -3A, I <sub>B</sub> = -300mA
Transition Frequency	f <sub>T</sub>	-	250	-	MHz	$I_C = -100 \text{mA}, V_{CE} = -5 \text{V},$ f = 100 MHz
Collector Output Capacitance (Note 9)	C <sub>OBO</sub>	-	17.6	30	pF	V <sub>CB</sub> = -10V, f = 1MHz
Turn-on time	t <sub>(on)</sub>	-	26.5	-	ns	V <sub>CC</sub> = -10V, I <sub>C</sub> = -500mA,
Turn-off time	t <sub>(off)</sub>	-	291	-	ns	$I_{B1} = I_{B2} = -50 \text{mA}$

Notes: 9. Measured under pulsed conditions. Pulse width  $\leq$  300  $\mu$ s. Duty cycle  $\leq$  2%

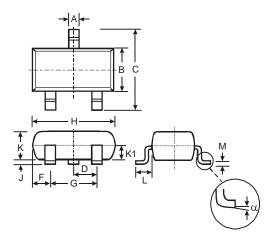


## **Typical Characteristics**



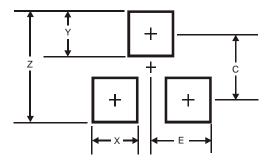


# **Package Outline Dimensions**



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
C	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.903	1.10	1.00		
K1	-	-	0.400		
L	0.45	0.61	0.55		
М	0.085	0.18	0.11		
α	0°	8°	-		
All Dimensions in mm					

## **Suggested Pad Layout**



Dimensions	Value (in mm)		
Z	2.9		
Х	0.8		
Υ	0.9		
С	2.0		
E	1.35		





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